DIFFERENTIAL VIDEO AMPLIFIER

FEATURES

- **Adjustable Gain to 400 (Typ)**
- **No Frequency Compensation Required**
- **Low Noise . . . 3-mV V_n (Typ)**

DESCRIPTION

This device is a monolithic two-stage video amplifier with differential inputs and differential outputs. It features internal series-shunt feedback that provides wide bandwidth, low phase distortion, and excellent gain stability. Emitter-follower outputs enable the device to drive capacitive loads. All stages are current-source biased to obtain high common-mode and supply-voltage rejection ratios.

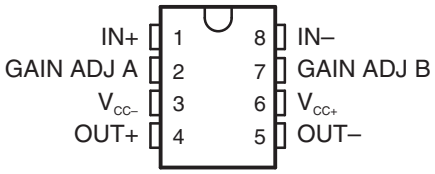
The differential gain is typically 400 when the gain adjust pins are connected together, or amplification may be adjusted for near 0 to 400 by the use of a single external resistor connected between the gain adjustment pins A and B. No external frequency-compensating components are required for any gain option.

The device is particularly useful in magnetic-tape or disk-file systems using phase or NRZ encoding and in high-speed thin-film or plated-wire memories. Other applications include general-purpose video and pulse amplifiers.

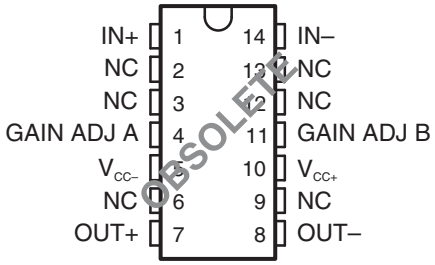
The device achieves low equivalent noise voltage through special processing and a new circuit layout incorporating input transistors with low base resistance.

The TL592B is characterized for operation from 0°C to 70°C.

D8, P, OR PS PACKAGE
(TOP VIEW)



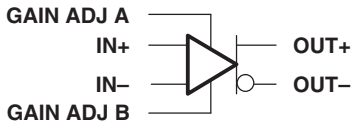
D14 OR N PACKAGE
(TOP VIEW)



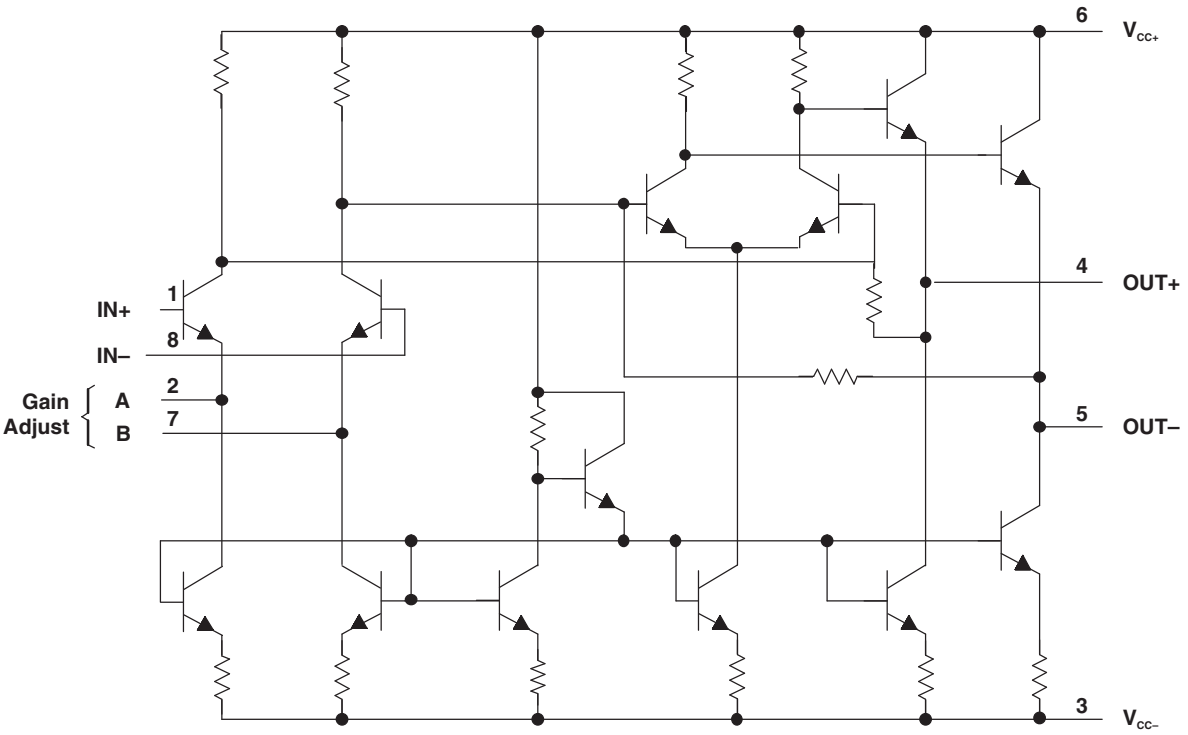
NC – No internal connection

Note: D8 and D14 are the codes to differentiate the 8-pin and 14-pin versions, respectively.

SYMBOL



SCHEMATIC



NOTE: Pin numbers shown are for D, P, and PS packages.

ABSOLUTE MAXIMUM RATINGS(1)(2)

over operating free-air temperature range (unless otherwise noted)

V_{CC+}	Positive supply voltage	8 V
$V_{CC–}$	Negative supply voltage	–8 V
V_{DI}	Differential input voltage	±5 V
V_I	Voltage range, any input	V_{CC+} to $V_{CC–}$
I_O	Output current	10 mA
P_D	Continuous total power dissipation	See Dissipation Rating Table
T_A	Operating free-air temperature range	0°C to 70°C
T_{stg}	Storage temperature range	–65°C to 150°C
T_{lead}	Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

(1) Stresses beyond those listed under *absolute maximum ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values except differential input voltages are with respect to the midpoint between V_{CC+} and $V_{CC–}$.

DISSIPATION RATINGS

PACKAGE	$T_A \le 25°C$ POWER RATING	DERATING FACTOR	DERATE ABOVE T_A	$T_A = 70°C$ POWER RATING
D8	530 mW	5.8 mW/°C	59	464 mW
D14	530 mW	N/A	N/A	530 mW
N	530 mW	N/A	N/A	530 mW
P	530 mW	N/A	N/A	530 mW
PS	530 mW	N/A	N/A	530 mW

RECOMMENDED OPERATING CONDITIONS

		MIN	NOM	MAX	UNIT
V_{CC+}	Positive supply voltage	3	6	8	V
V_{CC-}	Negative supply voltage	–3	–6	–8	V
T_A	Operating free-air temperature	0		70	°C

ELECTRICAL CHARACTERISTICS

at specified free-air temperature, $V_{CC\pm}$ = ±6 V, R_L = 2 kΩ (unless otherwise noted)

PARAMETER		TEST FIGURE	TEST CONDITIONS(1)		T_A	MIN	TYP	MAX	UNIT
A_{VD}	Large-signal differential voltage amplification	1	V_{OPP} = 3 V, R_L = 2 kΩ	R_{AB} = 0	25°C	300	400	500	V/V
					0°C to 70°C	250		600	
				R_{AB} = 1 kΩ	25°C		13		
BW	Bandwidth (–3 dB)	2	V_{OPP} = 1 V, R_{AB} = 0		25°C		50		MHz
I_{IO}	Input offset current				25°C		0.4	5	µA
					0°C to 70°C			6	
I_{IB}	Input bias current				25°C		9	30	µA
					0°C to 70°C			40	
V_{ICR}	Common-mode input voltage range	3			25°C	±1			V
					0°C to 70°C	±1			
V_{OC}	Common-mode output voltage	1	R_L = ∞		25°C	2.4	2.9	3.4	V
V_{OO}	Output offset voltage	1	V_{ID} = 0, R_{AB} = ∞, R_L = ∞		25°C		0.35	0.75	V
					0°C to 70°C			1.5	
V_{OPP}	Peak-to-peak output voltage swing	1	R_L = 2 kΩ, R_{AB} = 0		25°C	3	4		V
					0°C to 70°C	2.8			
r_i	Input resistance		V_{OD} = 1 V, R_{AB} = 0		25°C		4		kΩ
					0°C to 70°C		3.6		
r_o	Output resistance				0°C to 70°C			30	Ω
C_i	Input capacitance				0°C to 70°C		5		pF
CMRR	Common-mode rejection ratio	3	V_{IC} = ±1 V, R_{AB} = 0	f = 100 kHz	25°C	60	86		dB
				f = 5 MHz			60		
				f = 100 kHz	0°C to 70°C	50			
				f = 5 MHz			60		
k_{SVR}	Supply voltage rejection ratio ($\Delta V_{CC}/\Delta V_{IO}$)	4	ΔV_{CC+} = ±0.5 V, ΔV_{CC-} = ±0.5 V, R_{AB} = 0		25°C	50	70		dB
					0°C to 70°C	50			
V_n	Broadband equivalent input noise voltage	4	BW = 1 kHz to 10 MHz		25°C		3		µV
t_{pd}	Propagation delay time	2	ΔV_O = 1 V		25°C		7.5		ns
t_r	Rise time	2	ΔV_O = 1 V		25°C		10.5		ns
$I_{sink(max)}$	Maximum output sink current		V_{ID} = 1 V, V_O = 3 V			3	4		mA
I_{CC}	Supply current		No load, No signal		25°C		18	24	mA
					0°C to 70°C			27	

(1) R_{AB} is the gain-adjustment resistor connected between gain-adjust pins A and B. If not specified for a particular parameter, its value is irrelevant to that parameter.

PARAMETER MEASUREMENT INFORMATION

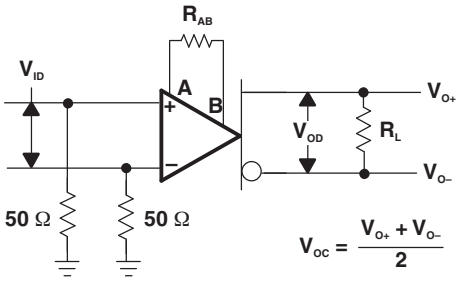


Figure 1.

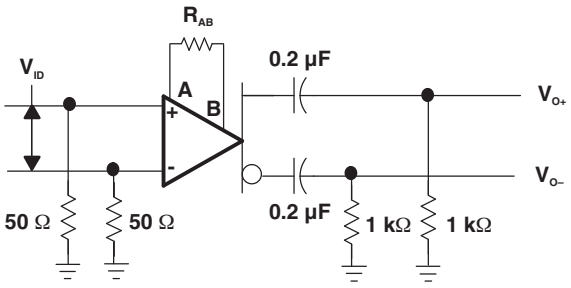


Figure 2.

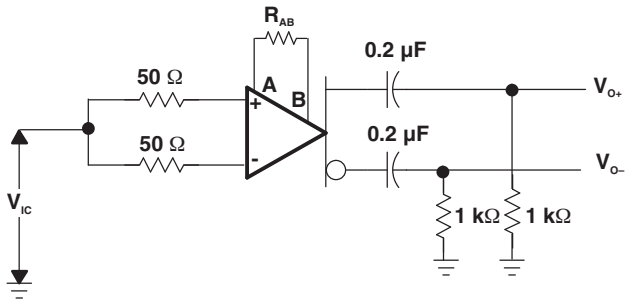


Figure 3.

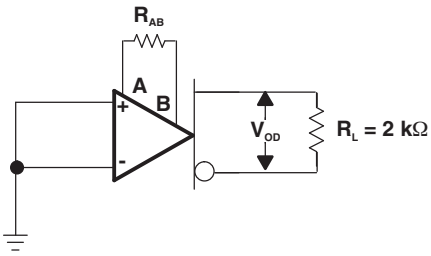


Figure 4.

TYPICAL CHARACTERISTICS

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION vs SUPPLY VOLTAGE

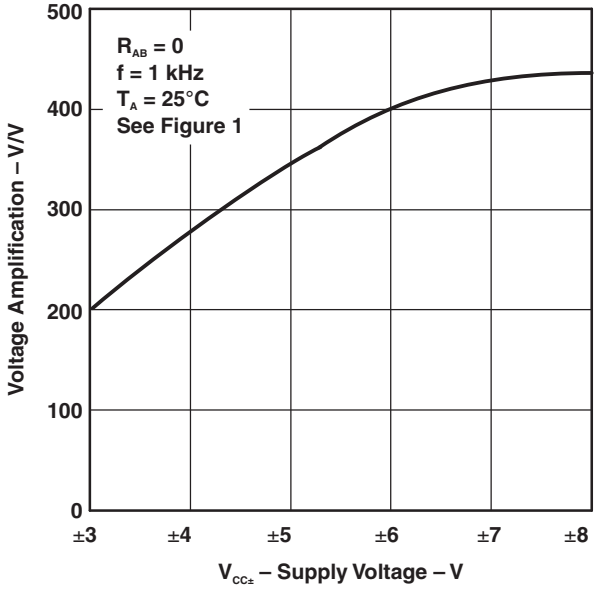


Figure 5.

LARGE-SIGNAL DIFFERENTIAL VOLTAGE AMPLIFICATION vs GAIN-ADJUSTMENT RESISTANCE

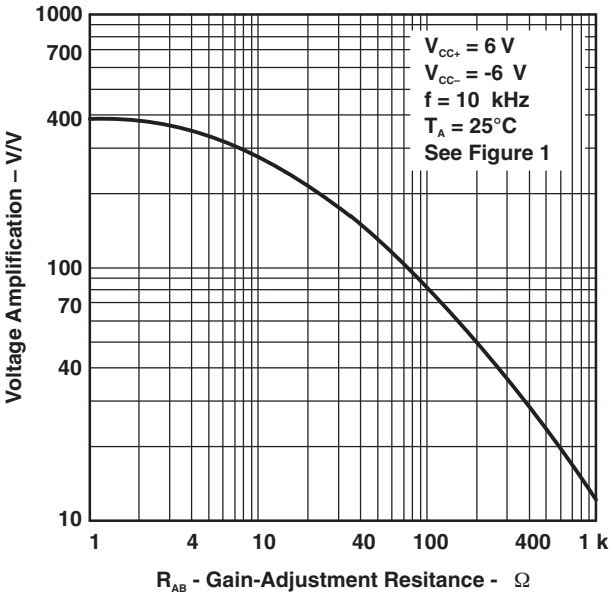


Figure 6.

SUPPLY CURRENT vs SUPPLY VOLTAGE

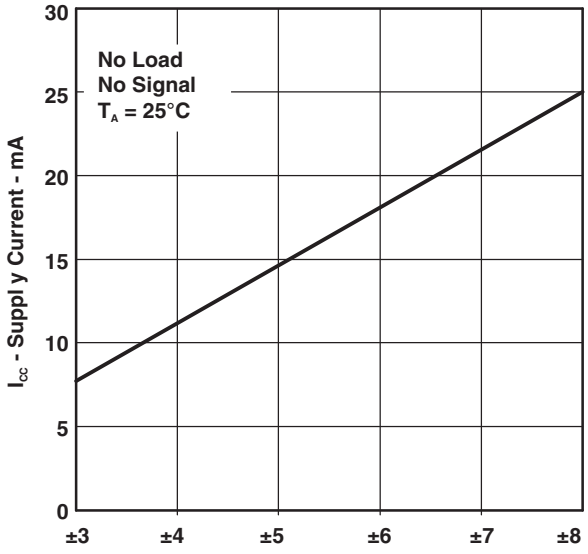


Figure 7.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TL592B-8D	ACTIVE	SOIC	D	8	75	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL592B	Samples
TL592B-8DR	ACTIVE	SOIC	D	8	2500	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	TL592B	Samples
TL592BP	ACTIVE	PDIP	P	8	50	RoHS & Green	NIPDAU	N / A for Pkg Type	0 to 70	TL592BP	Samples
TL592BPSR	ACTIVE	SO	PS	8	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	0 to 70	T592B	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals.
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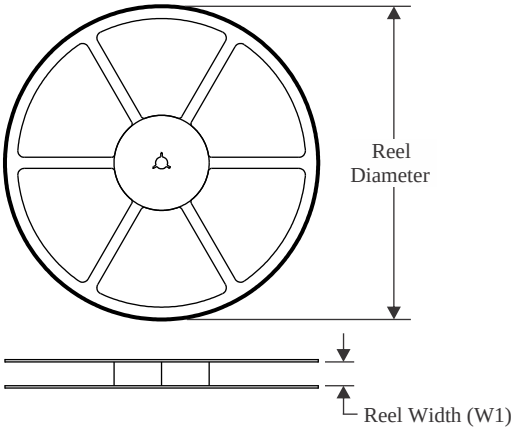
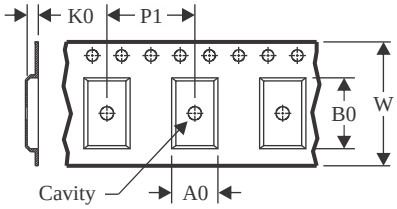
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

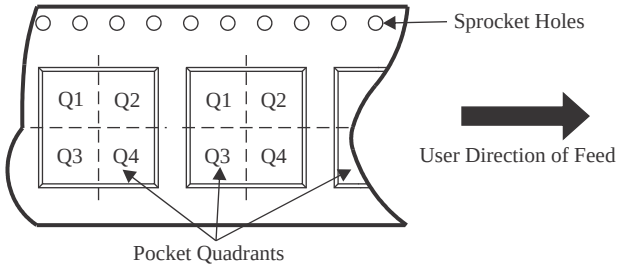


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

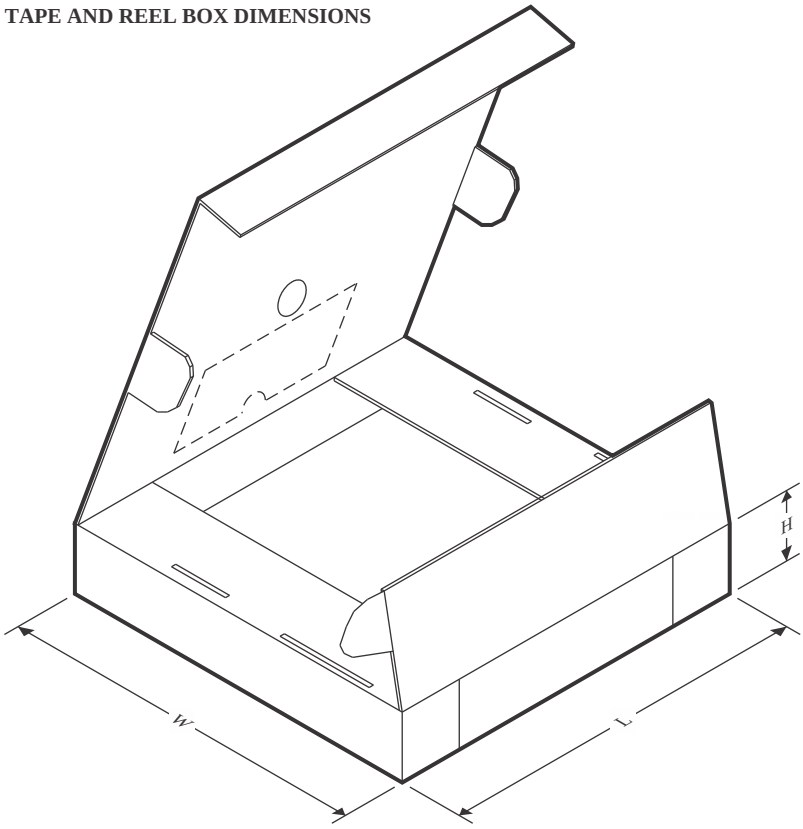
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TL592B-8DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL592BPSR	SO	PS	8	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1

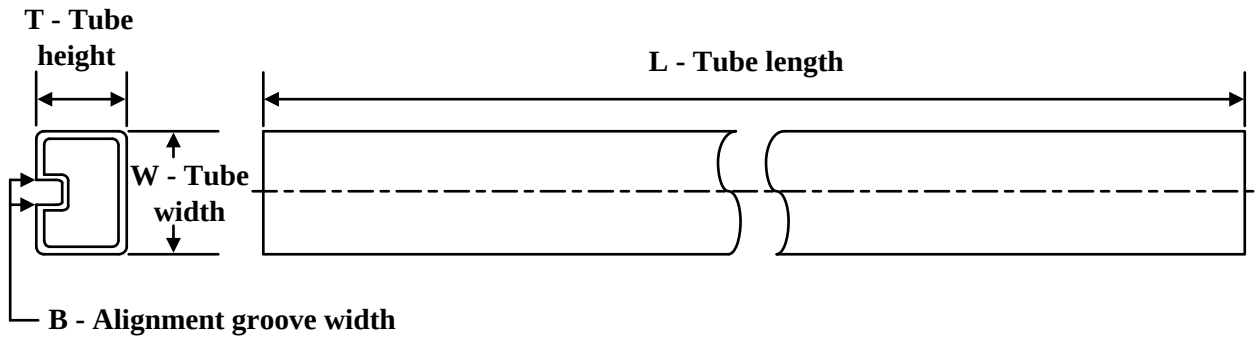
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

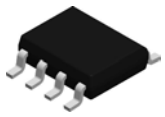
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TL592B-8DR	SOIC	D	8	2500	340.5	336.1	25.0
TL592BPSR	SO	PS	8	2000	356.0	356.0	35.0

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
TL592B-8D	D	SOIC	8	75	507	8	3940	4.32
TL592BP	P	PDIP	8	50	506	13.97	11230	4.32

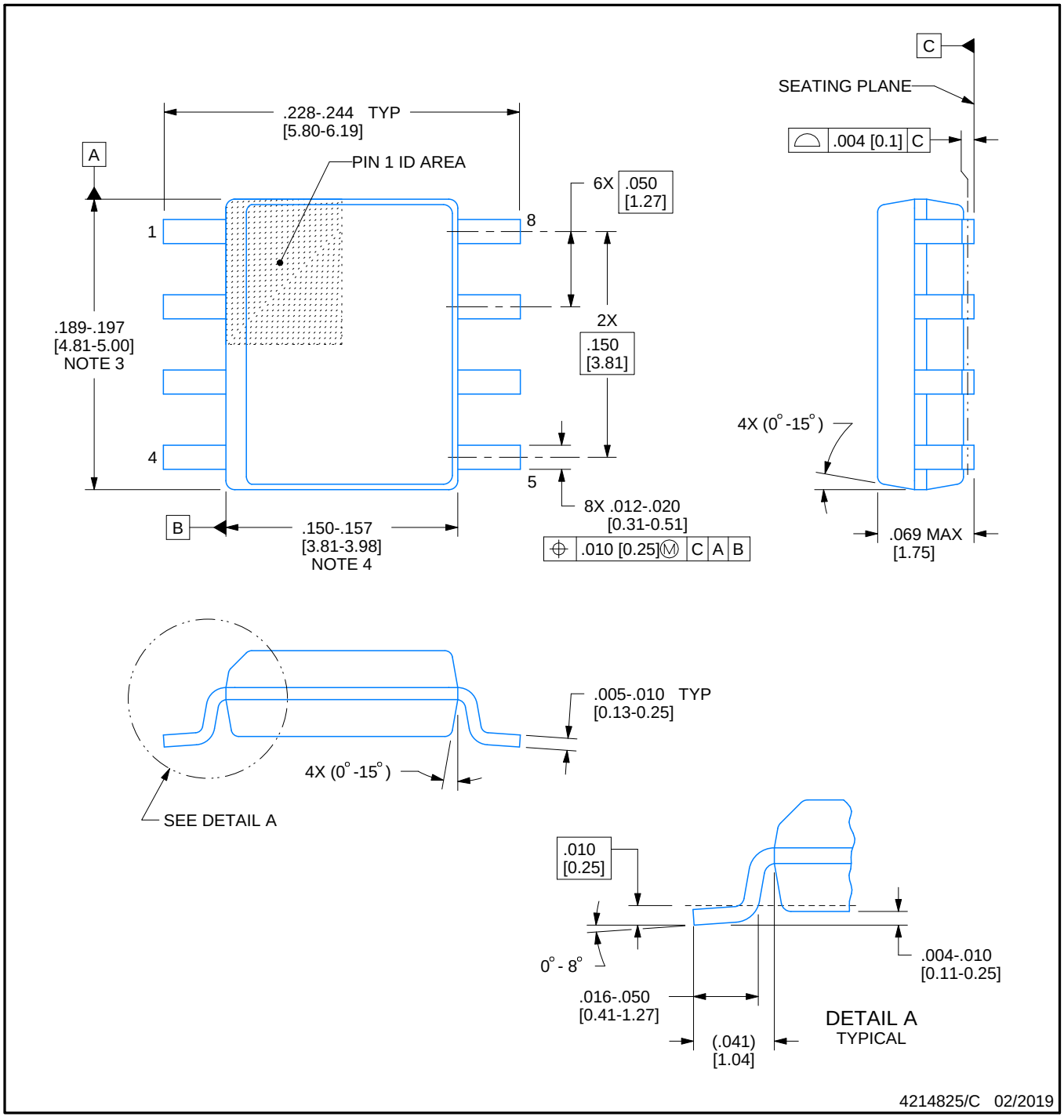


PACKAGE OUTLINE

D0008A

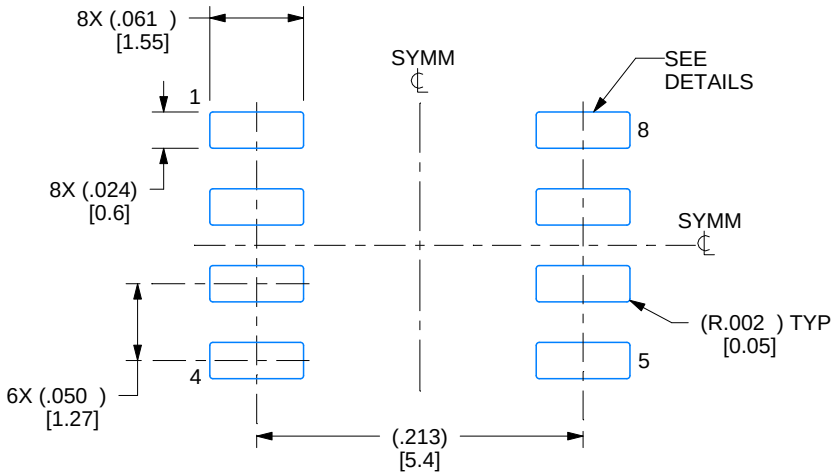
SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

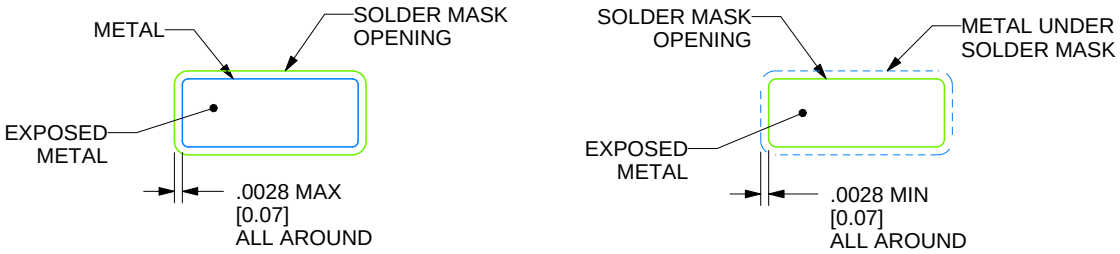


NOTES:

1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

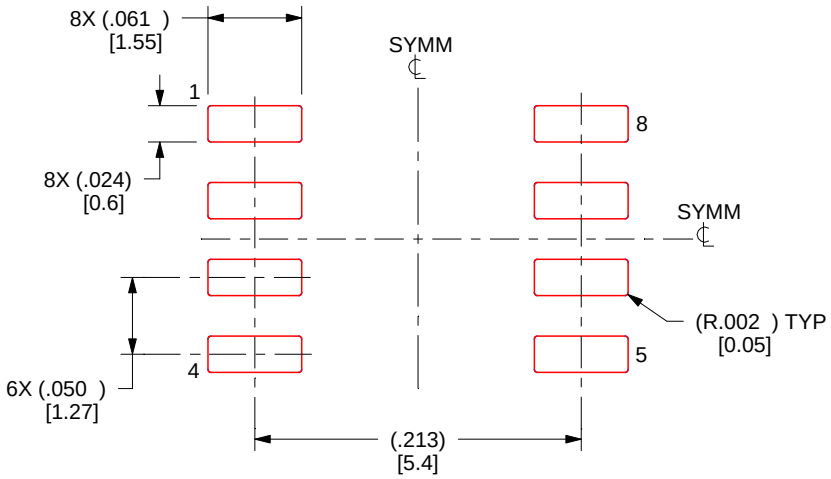
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

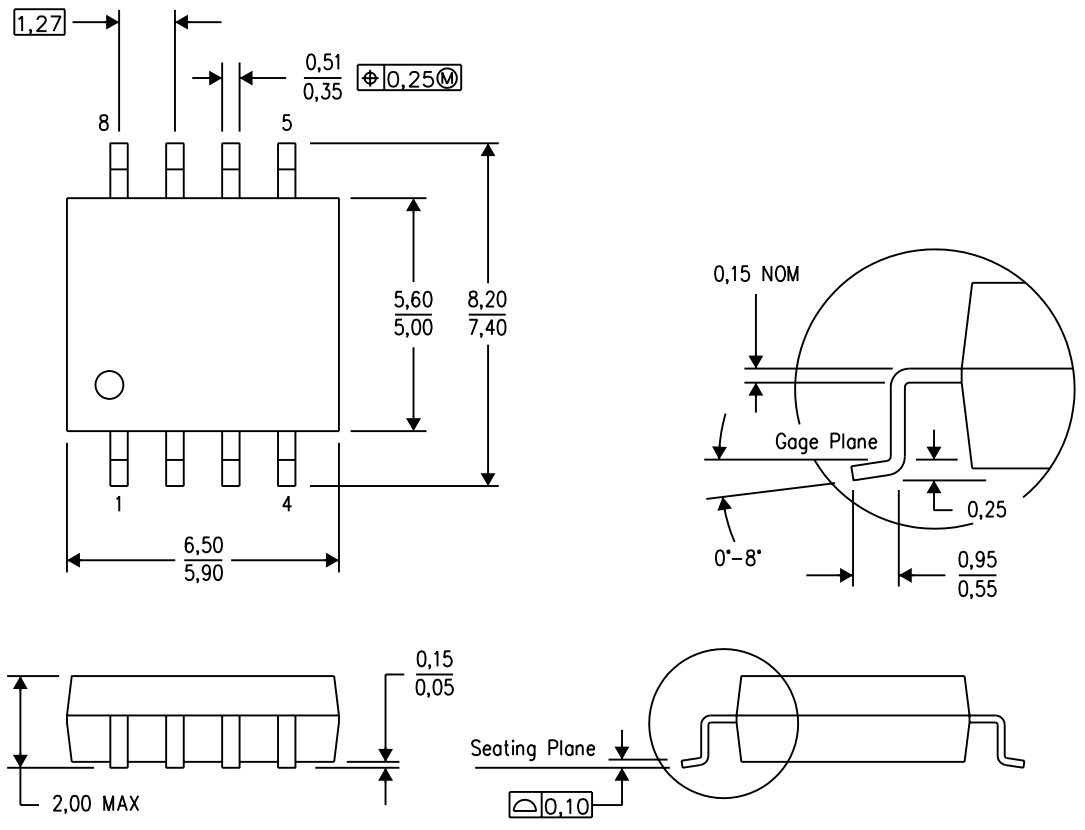
4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

MECHANICAL DATA

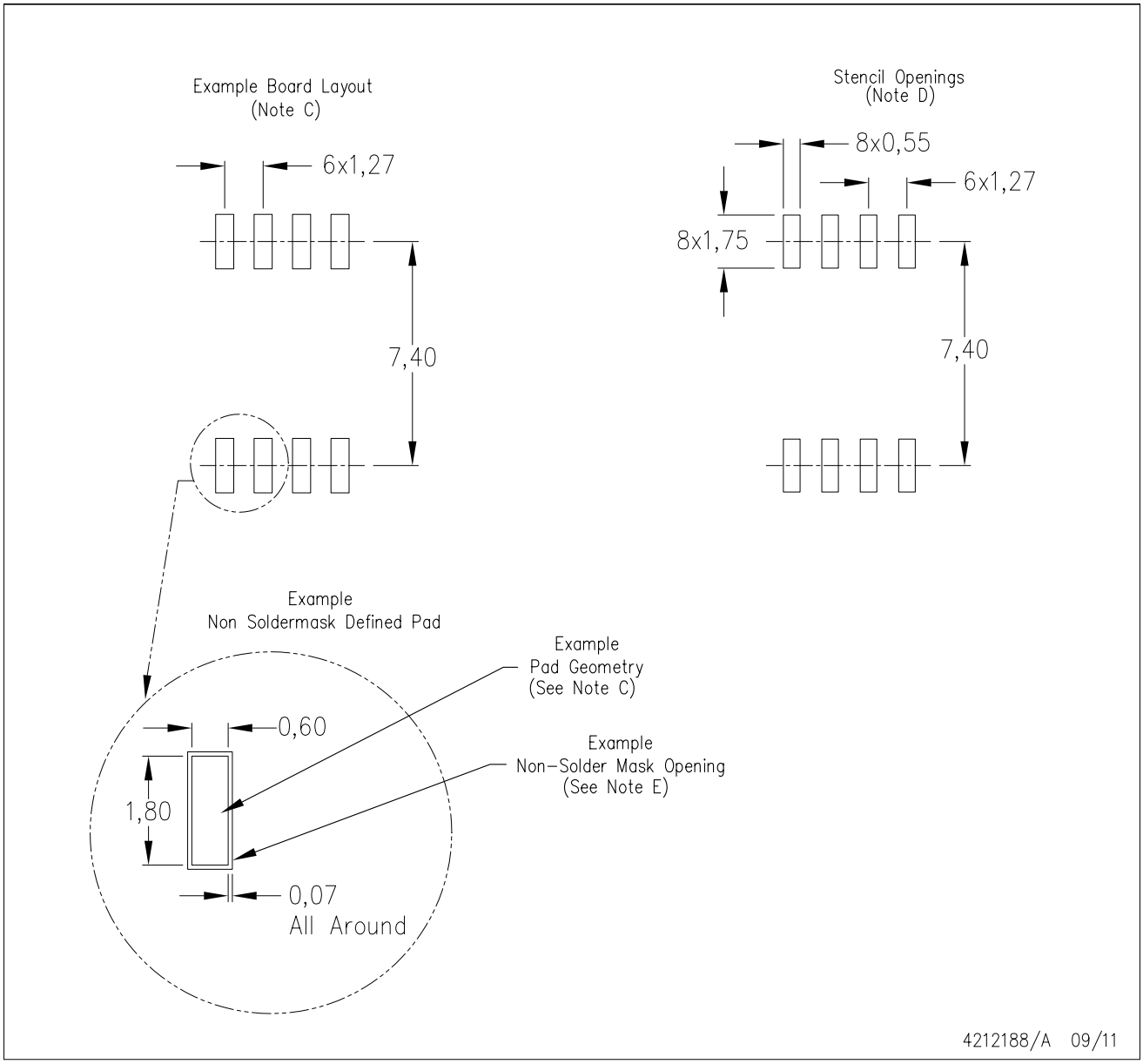
PS (R-PDSO-G8) **PLASTIC SMALL-OUTLINE PACKAGE**



4040063/C 03/03

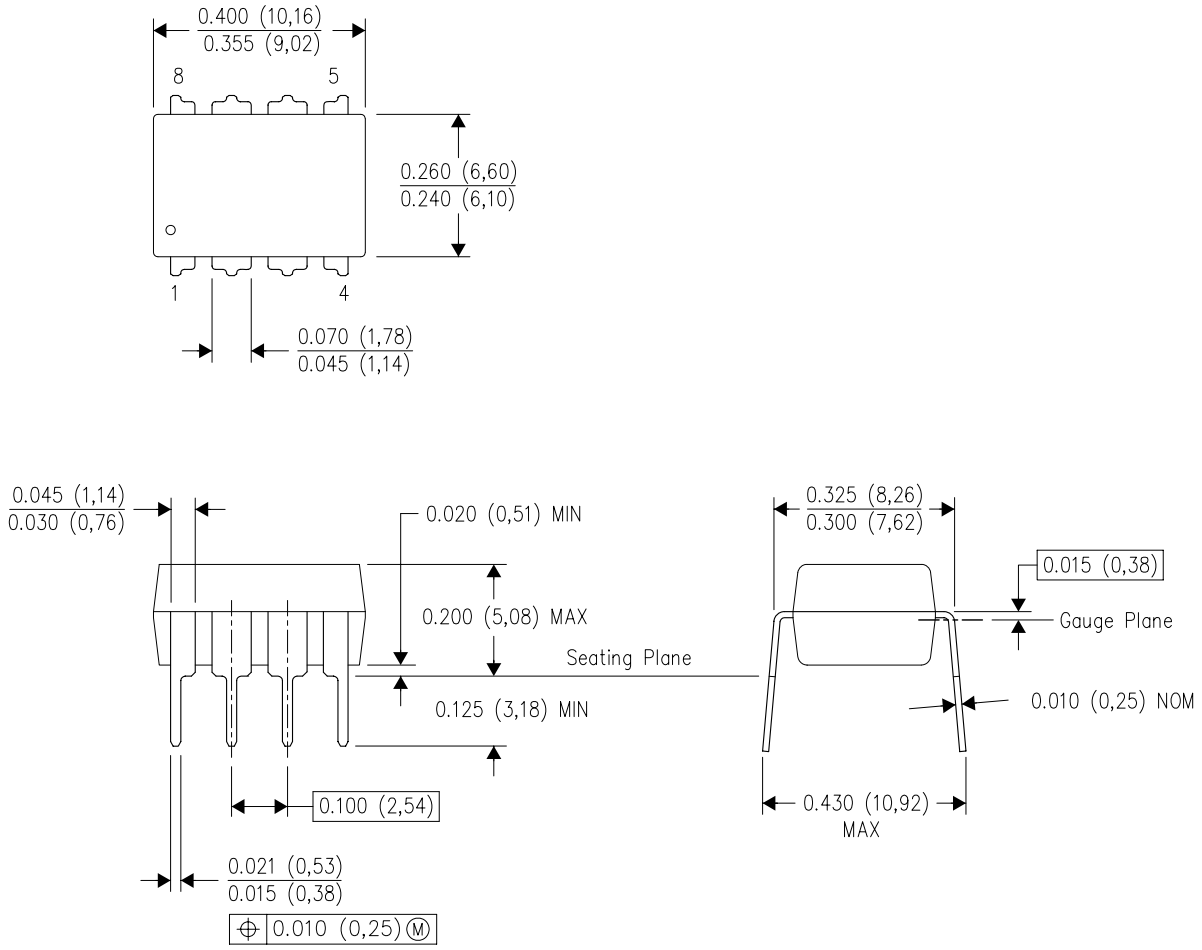
NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

PS (R–PDSO–G8) PLASTIC SMALL OUTLINE



NOTES:
A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Publication IPC–7351 is recommended for alternate designs.
D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC–7525 for other stencil recommendations.
E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.

P (R–PDIP–T8) PLASTIC DUAL–IN–LINE PACKAGE



NOTES:
A. All linear dimensions are in inches (millimeters).
B. This drawing is subject to change without notice.
C. Falls within JEDEC MS–001 variation BA.

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